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July 2016

FSA3030 — High-Speed USB2.0/Mobile High-Definition Link (MHL[™]) with Negative Swing Audio

Features

- Low On Capacitance: 4.2 pF/5 pF MHL/USB (Typical)
- Low Power Consumption: 30 µA Maximum
- Supports MHL Rev. 2.0
- MHL Data Rate: 4.0 Gbps
- Audio Swing: -1.5 V to +1.5 V (Typical)
- Packaged in 12-Lead UMLP (1.8 x 1.8 mm)
- Over-Voltage Tolerance (OVT) on all USB Ports Up to 5.25 V without External Components

Applications

Cell Phones and Digital Cameras

Description

The FSA3030 is a bi-directional, low-power, high-speed, 3:1, USB2.0, MHL[™] and audio switch. Configured as a double-pole, triple-throw (DP3T) switch, it is optimized for switching between high- or full-speed USB, Mobile High-Definition Link sources (per MHL Rev. 2.0 specification) and negative swing capable audio.

The FSA3030 contains special circuitry on the switch I/O pins, for applications where the V_{CC} supply is powered off (V_{CC} =0), that allows the device to withstand an over-voltage condition. This switch is designed to minimize current consumption even when the control voltage applied to the control pins is lower than the supply voltage (V_{CC}). This is especially valuable in mobile applications, such as cell phones, allowing direct interface with the general-purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, digital cameras, and notebook computers.

Ordering Information





Table 1. Data Switch Select Truth Table

SEL1 ⁽¹⁾	SEL0 ⁽¹⁾	Shunt	Function
0	0	Enable	D+/D- connected to USB+/USB-
0	1	Disable	D+/D- connected to R/L
1	0	Enable	D+/D- connected to MHL+/MHL
1	1	Enable	D+/D- High Impedance

Note:

Control inputs should never be left floating or unconnected. To guarantee default switch closure to the USB position, the SEL[0:1] pins should be tied to GND with a weak pull-down resistor (3 MΩ) to minimize static current draw.



Pin Definitions

Pin#	Name	Description
1	SEL0	Data Switch Select
2	SEL1	Data Switch Select
3	USB+	USB Differential Data (Positive)
4	USB-	USB Differential Data (Negative)
5	R	Audio Right
6	L	Audio Left
7	MHL+	MHL Differential Data (Positive)
8	MHL-	MHL Differential Data (Negative)
9	GND	Ground
10	D-	Data Switch Output (Positive)
11	D+	Data Switch Output (Negative)
12	V _{cc}	Device Power from System

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
Vcc	Supply Voltage	0	-0.5	6.0	V
V _{CNTRL}	DC Input Voltage (SEL[1:0]) ⁽²⁾		-0.5	V _{CC}	V
		USB	-0.5	Vcc	
$V_{SW}^{(3)}$	DC Switch I/O Voltage ⁽²⁾	MHL	-0.5	V _{CC}	V
		AUDIO	-2.0	3	
I _{IK}	DC Input Diode Current		-50		mA
		USB	1	60	mA
IOUT	Switch DC Output Current (Continuous)	MHL		60	mA
		AUDIO		60	mA
		USB		150	mA
IOUTPEAK	Switch DC Output Peak Current (Pulsed at 1 ms Duration, <10% Duty Cycle)	MHL		150	mA
		AUDIO		150	mA
T _{STG}	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level: JEDEC J-STD-020A			1	
	IEC 61000-4-2, Level 4, for D+/D- and V _{CC} Pins ⁽⁴⁾	Contact		8	
500	IEC 61000-4-2, Level 4, for D+/D- and V _{CC} Pins ⁽⁴⁾	Air		15	
ESD	Human Body Model, JEDEC: JESD22-A114	All Pins		3.5	kV
	Charged Device Model, JESD22-C101			2	

Notes:

2. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

3. V_{SW} refers to analog data switch paths (USB, MHL, and audio).

4. Testing performed in a system environment using TVS diodes.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	2.5	4.5	V
t _{RAMP(VCC)}	Power Supply Slew Rate	100	1000	µs/V
Θ_{JA}	Thermal Resistance		230	°C/W
V _{CNTRL}	Control Input Voltage (SEL[1:0]) ⁽⁵⁾	0	4.5	V
V _{SW(USB)}	Switch I/O Voltage (USB Switch Path)	-0.5	3.6	V
V _{SW(MHL)}	Switch I/O Voltage (MHL Switch Path)	1.65	3.45	V
V _{SW(AUD)}	Switch I/O Voltage (Audio Switch Path)	-1.5	3.0	V
T _A	Operating Temperature	-40	+85	°C

Note:

5. The control inputs must be held HIGH or LOW; they must not float.

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DC Electrical Characteristics

All typical value are at $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Paramotor	Condition	V AA	T _A =- 4	10°C to	+85°C	Unit
Symbol	Parameter	Condition	V _{cc} (V)	Min.	Тур.	Max.	Unit
VIK	Clamp Diode Voltage	I _{IN} =-18 mA	2.5			-1.2	V
VIH	Control Input Voltage High SEL[1:0]		2.5 to 4.50	1.0			V
VIL	Control Input Voltage Low SEL[1:0]		2.5 to 4.50			0.5	V
l _{in}	Control Input Leakage SEL[1:0]	V_{SW} (USB/MHL)=0 to 3.6 V, V_{SW} (AUD)=0 to 3.0 V, V_{CNTRL} =0 to V_{CC}	4.5	-0.5		0.5	μA
I _{OZ(MHL)}	Off-State Leakage for Open MHL Data Paths	$\label{eq:sws_sws_star} \begin{array}{l} V_{SW} {=} 1.65 \leq MHL \leq 3.45 \ V \\ \textbf{SEL} [1:0] {=} V_{CC} \end{array}$	4.5	-1		1	μA
I _{OZ(USB)}	Off-State Leakage for Open USB Data Paths	$\label{eq:sws_sws_star} \begin{array}{l} V_{SW} {=} 0 \leq USB \leq 3.6 \ V \\ SEL[1:0] {=} V_{CC} \end{array}$	4.5	-0.5		0.5	μA
I _{CL(MHL)}	On-State Leakage for Closed MHL Data Paths ⁽⁶⁾	$\label{eq:SW} \begin{array}{l} V_{SW} = 1.65 \leq \mbox{ MHL} \\ \leq 3.45 \mbox{ V, SEL0} = \mbox{ GND,} \\ \mbox{ SEL1} = V_{CC}, \mbox{ Other Side of} \\ \mbox{ Switch Float} \end{array}$	4.5	-0.75		0.75	μA
I _{CL(USB)}	On-State Leakage for Closed USB Data Paths ⁽⁶⁾	$\label{eq:sws_sws_star} \begin{array}{l} V_{SW} = 0 \leq USB \leq 3.6 \ V \\ SEL[1:0] = GND, \ Other \\ Side \ of \ Switch \ Float \end{array}$	4.5	-0.75		0.75	μA
I _{CL(AUD)}	On-State Leakage for Closed ⁽⁶⁾ AUDIO Data Path	$\label{eq:SW} \begin{array}{l} V_{SW}\mbox{=-}1.5 \leq R/L \leq 1.5 \ V \\ SEL1\mbox{=}GND, \ SEL0\mbox{=}V_{CC}, \\ Other \ Side \ of \ Switch \ Float \end{array}$	4.5	-1.0		1.0	μA
I _{OFF}	Power-Off Leakage Current (All I/O Ports)	VSW(USB/MHL)=0 to 3.6 V, VSW(AUD)=0 to 3.0 V, Figure 5	0	-1		1	μA
R _{ON(USB)}	HS Switch On Resistance (USB to D Path)	V _{SW} =0.4 V, I _{ON} =-8 mA, SEL[1:0]=GND, Figure 6	2.5		4.5		Ω
R _{ON(MHL)}	HS Switch On Resistance (MHL to D Path)	$V_{SW}=V_{CC}$ -1050 mV, SEL0=GND, SEL1= V_{CC} I _{ON} =-8 mA, Figure 6	2.5		5		Ω
R _{ON(Audio)}	Audio Switch On Resistance (R/L Path)	V_{SW} = -1.5 V to 1.5 V, SEL1=GND, SEL0=V _{CC} , I _{ON} =-24 mA, Figure 6	2.5		4		Ω
$\Delta R_{ON(MHL)}$	Difference in R _{ON} Between MHL Positive-Negative	$\label{eq:sws_sws_constraint} \begin{array}{l} V_{SW} = V_{CC} \text{-} 1050 \text{ mV},\\ \text{SEL0} = \text{GND}, \text{SEL1} = V_{CC},\\ \text{I}_{ON} = \text{-} 8 \text{ mA}, \text{ Figure 6}, \end{array}$	2.5		0.03		Ω
$\Delta R_{\text{ON(USB)}}$	Difference in R _{ON} Between USB Positive-Negative	V _{SW} =0.4 V, I _{ON} = -8 mA, SEL[1:0]=GND, Figure 6	2.5		0.18	-	Ω
$R_{\text{ONF}(\text{MHL})}$	Flatness for R _{ON} MHL Path	$\label{eq:swstar} \begin{array}{l} V_{SW} = 1.65 \text{ to } 3.45 \text{V}, \\ \text{SEL0} = \text{GND}, \text{SEL1} = V_{CC}, \\ I_{ON} = -8 \text{ mA}, \text{ Figure } 6 \end{array}$	2.5		1		Ω
R _{onfa(audio)}	Flatness for R _{ON} Audio Path	$\label{eq:sws-1.5} \begin{array}{l} V_{\text{SW}}{=}{-}1.5 \ V \ \text{to} \ 1.5 \ V, \\ \text{SEL1=GND, SEL0=} V_{\text{CC}}, \\ I_{\text{ON}}{=}{-}24 \ \text{mA, Figure 6} \end{array}$	2.5		0.1		Ω
R _{SH}	Shunt Resistance		3.6		125	200	Ω
I _{CC}	Quiescent Current	V _{CNTRL} =0 or 4.5 V, I _{OUT} =0	4.5			30	μA
ICCT	Delta Increase in Quiescent	V _{CNTRL} =1.65 V, I _{OUT} =0	4.5			18	μA
-	Current per Control Pin	V _{CNTRL} =2.5 V, I _{OUT} =0	4.5			10	-

Note:

6. For this test, the data switch is closed with the respective switch pin floating.

AC Electrical Characteristics

All typical values are for $V_{CC}{=}3.3$ V and $T_{A}{=}25^{\circ}C$ unless otherwise specified.

	Deremeter	Condition	V 00	T _A =- 4	0°C to	+85°C	11
Symbol	Parameter	Condition	V _{cc} (V)	Min.	Тур.	Max.	Unit
t _{ONUSB}	USB Turn-On Time, SEL[1:0] to Output	$\begin{array}{l} R_L{=}50 \ \Omega, \ C_L{=}5 \ p\text{F}, \ V_{SW(USB)}{=}0.8 \ V, \\ V_{SW(MHL)}{=}3.3 \ V, \ V_{SW(AUD)}{=}1.5 \ V, \\ Figure \ 7, \ Figure \ 8 \end{array}$	2.5 to 3.6		445	600	ns
t _{OFFUSB}	USB Turn-Off Time, SEL[1:0] to Output	$ \begin{array}{l} R_{L}{=}50 \ \Omega, \ C_{L}{=}5 \ pF, \ V_{SW(USB)}{=}0.8 \ V, \\ V_{SW(MHL)}{=}3.3 \ V, \ V_{SW(AUD)}{=}1.5 \ V, \\ Figure \ 7, \ Figure \ 8 \end{array} $	2.5 to 3.6		445	600	ns
t _{ONAUD}	AUDIO Turn-On Time, SEL[1:0] to Output	$ \begin{array}{l} R_{L} {=} 50 \ \Omega, \ C_{L} {=} 5 \ PF, \ V_{SW(USB)} {=} 0.8 \ V, \\ V_{SW(MHL)} {=} 3.3 \ V, \ V_{SW(AUD)} {=} 1.5 \ V, \\ Figure \ 7, \ Figure \ 8 \end{array} $	2.5 to 3.6		445	600	ns
toffaud	AUDIO Turn-Off Time, SEL[1:0] to Output	$\begin{array}{l} {\sf R}_{\sf L}{=}50\ \Omega,\ {\sf C}_{\sf L}{=}5p\ {\sf F},\ {\sf V}_{{\sf SW}({\sf USB})}{=}0.8\ {\sf V},\\ {\sf V}_{{\sf SW}({\sf MHL})}{=}3.3\ {\sf V},\ {\sf V}_{{\sf SW}({\sf AUD})}{=}1.5\ {\sf V},\\ {\sf Figure\ 7,\ Figure\ 8} \end{array}$	2.5 to 3.6		445	600	ns
t _{ONMHL}	MHL Turn-On Time, SEL[1:0] to Output	$ \begin{array}{l} R_{L} = \! 50 \; \Omega, \; C_{L} \! = \! 5 \; pF, \; V_{SW(USB)} \! = \! 0.8 \; V, \\ V_{SW(MHL)} \! = \! 3, \; V_{SW(AUD)} \! = \! 1.5 \; V, \\ Figure \; 7, \; Figure \; 8 \end{array} $	2.5 to 3.6		445	600	ns
toffmhl	MHL Turn-Off Time, SEL[1:0] to Output	$ \begin{array}{l} R_{L} {=} 50 \ \Omega, \ C_{L} {=} 5 \ pF, \ V_{SW(USB)} {=} 0.8 \ V, \\ V_{SW(MHL)} {=} 3.3 \ V, \ V_{SW(AUD)} {=} 1.5 \ V, \\ Figure \ 7, \ Figure \ 8 \end{array} $	2.5 to 3.6		445	600	ns
t _{PD}	Propagation Delay ⁽⁷⁾	$C_L=5 \text{ pF}, R_L=50 \Omega$, Figure 7, Figure 9	2.5 to 3.6		0.25		ns
t _{BBM}	Break-Before-Make ⁽⁷⁾	R_L =50 Ω, C_L =5 pF, V_{AUD} =1.5 V, V_{MHL} =3.3 V, V_{USB} =0.8 V, Figure 10	2.5 to 3.6		350		ns
O _{IRR(MHL)}	Off Isolation ⁽⁷⁾	V_{s} =1 V_{pk-pk} , R_{L} =50 Ω , f=240 MHz, Figure 11	2.5 to 3.6		-33		dB
O _{IRR(USB)}	Off Isolation 7	V _S =400 mV _{pk-pk} , R _L =50 Ω, f=240 MHz, Figure 11	2.5 to 3.6		-38		dB
Xtalk _{MHL}		V_{s} =1 V_{pk-pk} , R_{L} =50 Ω , f=240 MHz, Figure 12	2.5 to 3.6		-44		dB
Xtalk _{USB}	Non-Adjacent Channel ⁽⁷⁾ Crosstalk	V _S =400 mV _{pk-pk} , R _L =50 Ω, f=240 MHz, Figure 12	2.5 to 3.6		-39	/	dB
Xtalk _{AUD}		V_{S} =100 m V_{RMS} , R _L =32 Ω , f=20 kHz, Figure 12	2.5 to 3.6		-70		dB
THD	Total Harmonic Distortion ⁽⁷⁾	R_T =32 Ω, V _{SW} =2 V _{pk-pk} , f=20 Hz to 20 kHz, V _{BIAS} =0 V	2.5		0.01		%
		$ \begin{array}{l} V_{\text{IN}} = 1 \ V_{\text{pk-pk}}, \ \text{Common Mode} \\ \text{Voltage} = V_{\text{CC}} - 1.1 \ \text{V}, \ \text{MHL Path}, \\ \text{R}_{\text{L}} = 50 \ \Omega, \ \text{C}_{\text{L}} = 0 \ \text{pF}, \ \text{Figure 13} \end{array} $			2.0	G	GHz
BW	S _{DD21} Differential -3 db Bandwidth ⁽⁷⁾	V_{IN} =400 m V_{pk-pk} , Common Mode Voltage=0.2 V, USB Path, R _L =50 Ω , C _L =0 pF, Figure 13	2.5 to 3.6		1.80	U	GHZ
		AUDIO Path, $R_L=50 \Omega$, $C_L=0 pF$			50		MHz

Note:

7. Guaranteed by characterization.

USB High-Speed AC Electrical Characteristics

All typical value are at T_A=25°C unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	Тур.	Unit
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽⁸⁾	$C_L=5 \text{ pF}, R_L=50 \Omega$, Figure 14	3.0 to 3.6	3	ps
tj	Total Jitter ⁽⁸⁾	R _L =50 Ω, C _L =5 pf, t _R =t _F =500 ps (10-90%) at 480 Mbps, PN7	3.0 to 3.6	15	ps

Note:

8. Guaranteed by characterization.

MHL AC Electrical Characteristics

All typical value are at T_A=25°C unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	Тур.	Unit
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽⁹⁾	$R_{\text{PU}}\text{=}50~\Omega$ to $V_{\text{CC}},C_{\text{L}}\text{=}0~\text{pF}$	3.0 to 3.6	3	ps
tJ	Total Jitter ⁽⁹⁾	f=2.25 Gbps, PN7, R _{PU} =50 Ω to V _{CC} , C _L =0 pF	3.0 to 3.6	26	ps

Note:

9. Guaranteed by characterization.

Capacitance

All typical value are at T_A=25°C unless otherwise specified.

Symbol	Parameter	Condition	Тур.	Unit
C _{IN}	Control Pin Input Capacitance ⁽¹⁰⁾	V _{CC} =0 V, f=1 MHz	1.5	
C _{ON(USB)}	USB Path On Capacitance ⁽¹⁰⁾	V _{CC} =3.3 V, f=240 MHz, Figure 15	6.5	V
C _{OFF} (USB)	USB Path Off Capacitance ⁽¹⁰⁾	V _{CC} =3.3 V, f=240 MHz, Figure 16	2.5	
C _{ON(MHL)}	MHL Path On Capacitance ⁽¹⁰⁾	V _{CC} =3.3 V, f=240 MHz, Figure 15	6.5	pF
COFF(MHL)	MHL Path Off Capacitance ⁽¹⁰⁾	V _{CC} =3.3 V, f=240 MHz, Figure 16	2.5	
C _{ON(AUD)}	Audio Path On Capacitance ⁽¹⁰⁾	V _{CC} =3.3 V, f=1 MHz, Figure 15	8.0	
C _{OFF(AUD)}	Audio Path Off Capacitance ⁽¹⁰⁾	V _{CC} =3.3 V, f=1 MHz, Figure 16	2.5	

Note:

10. Guaranteed by characterization.







Functional Description

Insertion Loss

One of the key factors for using the FSA3030 in mobile digital video applications is the small amount of insertion loss experienced by the received signal as it passes through the switch. This results in minimal degradation of the received eye. One of the ways to measure the quality of the high data rate channels is using balanced ports and four-port differential S-parameter analysis, particularly SDD21.

Bandwidth is measured using the S-parameter SDD21 methodology.

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Figure 17. MHL Path SDD21 Insertion Loss Curve



Figure 18. USB Path SDD21 Insertion Loss Curve

Typical Applications

Figure 19 shows the FSA3030 utilizing the VBAT connection. The 3M resistors are used to ensure, for manufacturing test via the micro-USB connector, that the FSA3030 configures for connectivity to the baseband or application processor.



Figure 19. MHL Path SDD21 Insertion Loss Curve

able 2. P	roduct-Specific Package Dimension	s	
	Description	Nominal Values (mm)	
	Overall Height	0.50	
	Package Standoff	0.012	
	Lead Thickness	0.15	
	Lead Width	0.20	
	Lead Length	0.40	
	Lead Pitch	0.40	
	Body Length (X)	Min: 1.70, Nom: 1.80, Max: 1.90	
	Body Width (Y)	Min: 1.70, Nom: 1.80, Max: 1.90	
	Lead One Nominal Length	0.40	
	Lead One Nominal Width	0.20	
Le	ad One Nominal Bevel Length	0.10	
Le	ead One Nominal Bevel Depth	0.10	
Lead	One Nominal Tip Non-Bevel Width	0.10	



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